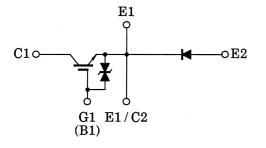
TOSHIBA GTR Module Silicon N Channel IGBT

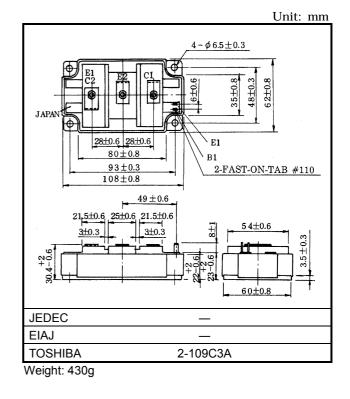
MG150Q1JS40

High Power Switching Applications Chopper Applications

- High input impedance
- High speed : $t_f = 0.5 \mu s$ (Max) $t_{rr} = 0.5 \mu s$ (Max)
- Low saturation voltage
- : VCE (sat) = 4.0V (Max)
- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit



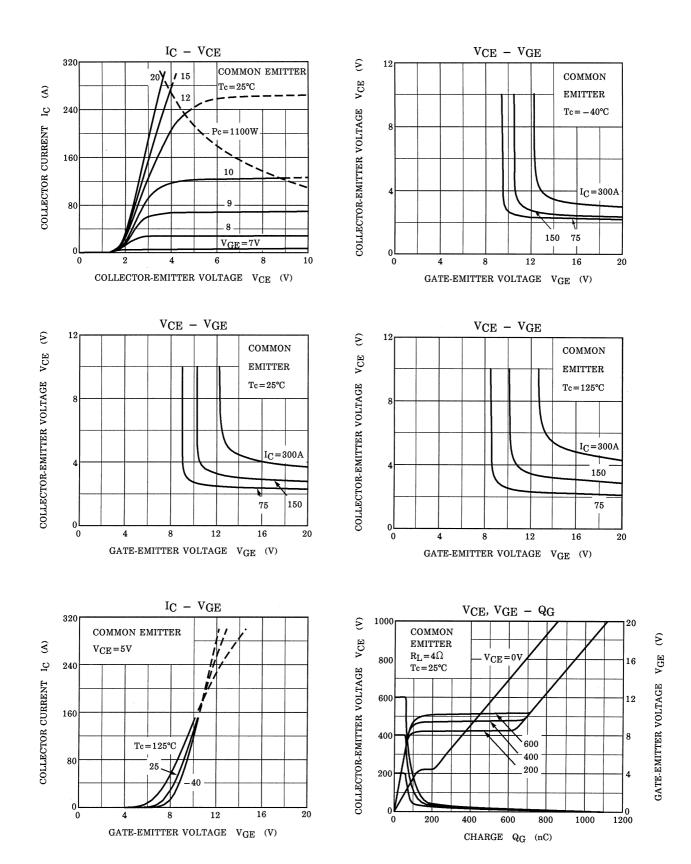


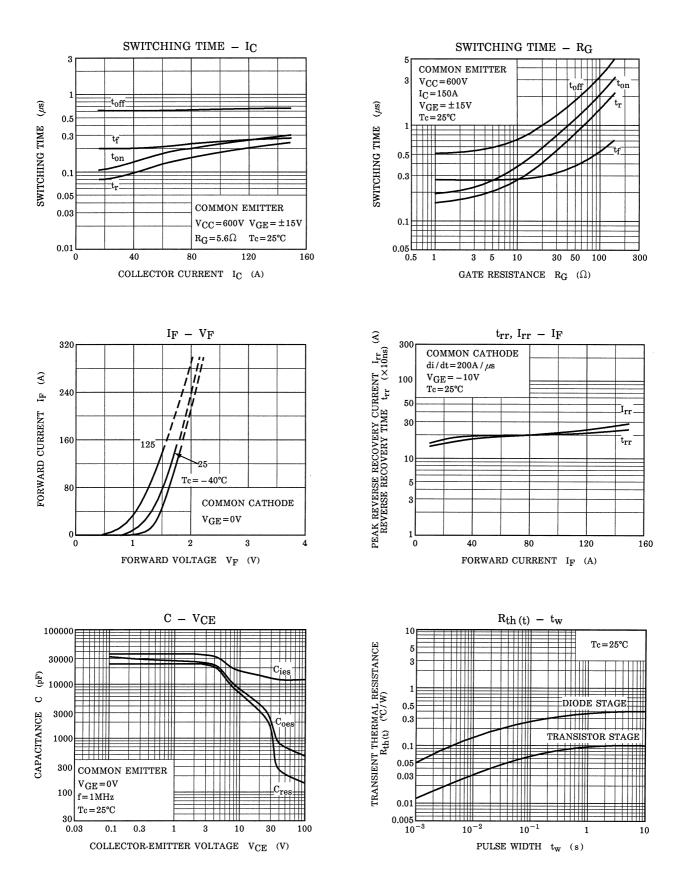
Maximum Ratings (Ta = 25°C)

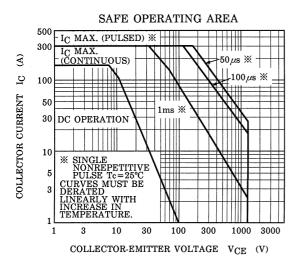
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	Ι _C	150	A	
	1ms	I _{CP}	300		
Forward current	DC	١ _F	150	A	
	1ms	I _{FM}	300		
Collector power dissipation (Tc = 25°C)		P _C	1100	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)		_	3/3	N∙m	

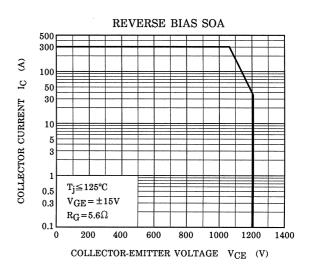
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	_	_	±20	μA
Collector cut-off current		ICES	V _{CE} = 1200V, V _{GE} = 0	_	_	2.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 150mA , V _{CE} = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 150A, V _{GE} = 15V	_	3.0	4.0	V
Input capacitance		Cies	V _{CE} = 10V, V _{GE} = 0, f = 1MHz	_	18000		pF
Switching time	Rise time	tr	$15V_{0}$	_	0.3	0.6	μs
	Turn-on time	t _{on}		_	0.4	0.8	
	Fall time	t _f		_	0.2	0.5	
	Turn-off time	t _{off}		_	0.8	1.5	
Forward voltage		V _F	I _F = 150A, V _{GE} = 0	_	2.0	3.0	V
Reverse recovery time		t _{rr}	I _F = 150A, V _{GE} = −10V di / dt = 200A / μs	_	0.25	0.5	μs
Thermal resistance	Transistor	R _{th (j-c)}	_	_	_	0.11	°C/W
	Diode	R _{th (j-c)}		_	_	0.4	









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